

# PROCEEDINGS OF SPIE

## **Semiconductor Lasers and Applications XII**

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**5-11 December 2022**  
**ONLINE, China**

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SPIE

**Volume 12311**

Proceedings of SPIE 0277-786X, V. 12311

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Please use the following format to cite material from these proceedings:

Author(s), "Title of Paper," in *Semiconductor Lasers and Applications XII*, edited by Wei Li, Werner H. Hofmann, Yikai Su, Proc. of SPIE 12311, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510656888

ISBN: 9781510656895 (electronic)

Published by

**SPIE**

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time)

[SPIE.org](http://SPIE.org)

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